NSN 5961-01-067-4961

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-067-4961 **Inclosure Material:** Metal or plastic **Overall Length:** 0.785 inches **Overall Height:** 0.200 inches **Overall Width:** 0.250 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** -40.0 collector to base voltage, dc all transistor and -40.0 collector to emitter voltage/static/base open all transistor and -5.0 emitter to base voltage, instantaneous all transistor **Current Rating Per Characteristic:** -1.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 6.3 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No